

# Quad 2-Input OR Gate With 5V-Tolerant Inputs

The MC74LVX32 is an advanced high speed CMOS 2-input OR gate. The inputs tolerate voltages up to 7V, allowing the interface of 5V systems to 3V systems.

- High Speed:  $t_{PD} = 4.4\text{ns}$  (Typ) at  $V_{CC} = 3.3\text{V}$
- Low Power Dissipation:  $I_{CC} = 2\mu\text{A}$  (Max) at  $T_A = 25^\circ\text{C}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Low Noise:  $V_{OLP} = 0.5\text{V}$  (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300mA
- ESD Performance: HBM > 2000V; Machine Model > 200V

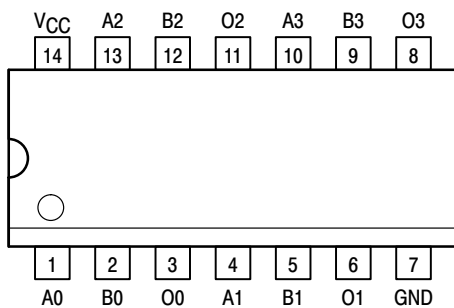


Figure 1. 14-Lead Pinout (Top View)

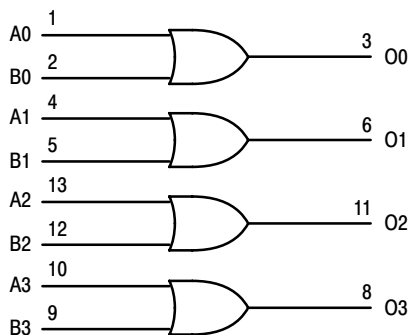


Figure 2. Logic Diagram

## MC74LVX32



**D SUFFIX**  
14-LEAD SOIC PACKAGE  
CASE 751A



**DT SUFFIX**  
14-LEAD TSSOP PACKAGE  
CASE 948G



**M SUFFIX**  
14-LEAD SOIC EIAJ PACKAGE  
CASE 965

### PIN NAMES

| Pins   | Function    |
|--------|-------------|
| An, Bn | Data Inputs |
| On     | Outputs     |

### FUNCTION TABLE

| INPUTS |    | OUTPUTS |
|--------|----|---------|
| An     | Bn | On      |
| L      | L  | L       |
| L      | H  | H       |
| H      | L  | H       |
| H      | H  | H       |

# MC74LVX32

## MAXIMUM RATINGS\*

| Symbol           | Parameter                                       | Value                        | Unit |
|------------------|---|------------------------------|------|
| V <sub>CC</sub>  | DC Supply Voltage                               | -0.5 to +7.0                 | V    |
| V <sub>in</sub>  | DC Input Voltage                                | -0.5 to +7.0                 | V    |
| V <sub>out</sub> | DC Output Voltage                               | -0.5 to V <sub>CC</sub> +0.5 | V    |
| I <sub>IK</sub>  | Input Diode Current                             | -20                          | mA   |
| I <sub>OK</sub>  | Output Diode Current                            | ±20                          | mA   |
| I <sub>out</sub> | DC Output Current, per Pin                      | ±25                          | mA   |
| I <sub>CC</sub>  | DC Supply Current, V <sub>CC</sub> and GND Pins | ±50                          | mA   |
| P <sub>D</sub>   | Power Dissipation                               | 180                          | mW   |
| T <sub>stg</sub> | Storage Temperature                             | -65 to +150                  | °C   |

\* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

## RECOMMENDED OPERATING CONDITIONS

| Symbol           | Parameter                                | Min | Max             | Unit |
|------------------|--|-----|-----------------|------|
| V <sub>CC</sub>  | DC Supply Voltage                        | 2.0 | 3.6             | V    |
| V <sub>in</sub>  | DC Input Voltage                         | 0   | 5.5             | V    |
| V <sub>out</sub> | DC Output Voltage                        | 0   | V <sub>CC</sub> | V    |
| T <sub>A</sub>   | Operating Temperature, All Package Types | -40 | +85             | °C   |
| Δt/ΔV            | Input Rise and Fall Time                 | 0   | 100             | ns/V |

## DC ELECTRICAL CHARACTERISTICS

| Symbol          | Parameter  | Test Conditions  | V <sub>CC</sub><br>V | T <sub>A</sub> = 25°C |     |      | T <sub>A</sub> = -40 to 85°C |      | Unit |
|-----------------|--|--|----------------------|-----------------------|-----|------|------------------------------|------|------|
|                 |  |  |                      | Min                   | Typ | Max  | Min                          | Max  |      |
| V <sub>IH</sub> | High-Level Input Voltage   |  | 2.0                  | 1.5                   |     |      | 1.5                          |      | V    |
|                 |  |  | 3.0                  | 2.0                   |     |      | 2.0                          |      |      |
|                 |  |  | 3.6                  | 2.4                   |     |      | 2.4                          |      |      |
| V <sub>IL</sub> | Low-Level Input Voltage  |  | 2.0                  |                       |     | 0.5  |                              | 0.5  | V    |
|                 |  |  | 3.0                  |                       |     | 0.8  |                              | 0.8  |      |
|                 |  |  | 3.6                  |                       |     | 0.8  |                              | 0.8  |      |
| V <sub>OH</sub> | High-Level Output Voltage<br>(V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub> ) | I <sub>OH</sub> = -50μA<br>I <sub>OH</sub> = -50μA<br>I <sub>OH</sub> = -4mA | 2.0                  | 1.9                   | 2.0 |      | 1.9                          |      | V    |
|                 |  |  | 3.0                  | 2.9                   | 3.0 |      | 2.9                          |      |      |
|                 |  |  | 3.0                  | 2.58                  |     |      | 2.48                         |      |      |
| V <sub>OL</sub> | Low-Level Output Voltage<br>(V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub> )  | I <sub>OL</sub> = 50μA<br>I <sub>OL</sub> = 50μA<br>I <sub>OL</sub> = 4mA    | 2.0                  |                       | 0.0 | 0.1  |                              | 0.1  | V    |
|                 |  |  | 3.0                  |                       | 0.0 | 0.1  |                              | 0.1  |      |
|                 |  |  | 3.0                  |                       |     | 0.36 |                              | 0.44 |      |
| I <sub>in</sub> | Input Leakage Current  | V <sub>in</sub> = 5.5V or GND  | 3.6                  |                       |     | ±0.1 |                              | ±1.0 | μA   |
| I <sub>CC</sub> | Quiescent Supply Current   | V <sub>in</sub> = V <sub>CC</sub> or GND                                     | 3.6                  |                       |     | 2.0  |                              | 20.0 | μA   |

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## AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0\text{ns}$ )

| Symbol                   | Parameter                          | Test Conditions  | $T_A = 25^\circ\text{C}$ |     |      | $T_A = -40 \text{ to } 85^\circ\text{C}$ |      | Unit |
|--------------------------|------------------------------------|--|--------------------------|-----|------|--|------|------|
|                          |                                    |  | Min                      | Typ | Max  | Min                                      | Max  |      |
| $t_{PLH}$ ,<br>$t_{PHL}$ | Propagation Delay, Input to Output | $V_{CC} = 2.7\text{V}$ $C_L = 15\text{pF}$   |                          | 5.8 | 10.7 | 1.0                                      | 13.5 | ns   |
|                          |                                    | $C_L = 50\text{pF}$  |                          | 8.3 | 14.2 | 1.0                                      | 17.0 |      |
|                          |                                    | $V_{CC} = 3.3 \pm 0.3\text{V}$ $C_L = 15\text{pF}$   |                          | 4.4 | 6.6  | 1.0                                      | 8.0  |      |
|                          |                                    | $C_L = 50\text{pF}$  |                          | 6.9 | 10.1 | 1.0                                      | 11.5 |      |
| $t_{OSHL}$<br>$t_{OSLH}$ | Output-to-Output Skew (Note 1.)    | $V_{CC} = 2.7\text{V}$ $C_L = 50\text{pF}$<br>$V_{CC} = 3.3 \pm 0.3\text{V}$ $C_L = 50\text{pF}$ |                          |     | 1.5  |  | 1.5  | ns   |

1. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW ( $t_{OSHL}$ ) or LOW-to-HIGH ( $t_{OSLH}$ ); parameter guaranteed by design.

## CAPACITIVE CHARACTERISTICS

| Symbol   | Parameter                               | $T_A = 25^\circ\text{C}$ |     |     | $T_A = -40 \text{ to } 85^\circ\text{C}$ |     | Unit |
|----------|---|--------------------------|-----|-----|--|-----|------|
|          |   | Min                      | Typ | Max | Min                                      | Max |      |
| $C_{in}$ | Input Capacitance                       |                          | 4   | 10  |  | 10  | pF   |
| $C_{PD}$ | Power Dissipation Capacitance (Note 2.) |                          | 14  |     |  |     | pF   |

2.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \cdot V_{CC} \cdot f_{in} + I_{CC}/4$  (per gate).  $C_{PD}$  is used to determine the no-load dynamic power consumption;  $P_D = C_{PD} \cdot V_{CC}^2 \cdot f_{in} + I_{CC} \cdot V_{CC}$ .

## NOISE CHARACTERISTICS (Input $t_r = t_f = 3.0\text{ns}$ , $C_L = 50\text{pF}$ , $V_{CC} = 3.3\text{V}$ , Measured in SOIC Package)

| Symbol    | Characteristic                           | $T_A = 25^\circ\text{C}$ |      | Unit |
|-----------|--|--------------------------|------|------|
|           |  | Typ                      | Max  |      |
| $V_{OLP}$ | Quiet Output Maximum Dynamic $V_{OL}$    | 0.3                      | 0.5  | V    |
| $V_{OLV}$ | Quiet Output Minimum Dynamic $V_{OL}$    | -0.3                     | -0.5 | V    |
| $V_{IHD}$ | Minimum High Level Dynamic Input Voltage |                          | 2.0  | V    |
| $V_{ILD}$ | Maximum Low Level Dynamic Input Voltage  |                          | 0.8  | V    |

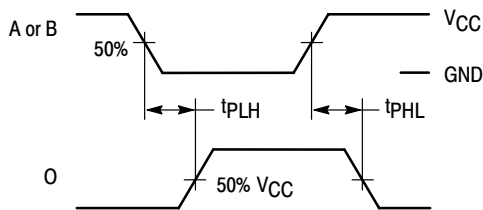
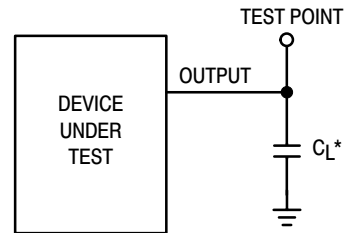


Figure 3. Switching Waveforms



\*Includes all probe and jig capacitance

Figure 4. Test Circuit